

# 2N5400



# **PNP General Purpose Amplifier**

This device is designed for use as general purpose amplifiers and switches requiring high voltages.

# **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
$V_{CEO}$	Collector-Emitter Voltage	120	V	
V <sub>CBO</sub>	Collector-Base Voltage	130	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V	
Ic	Collector Current - Continuous	600	mA	
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C	

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# **Thermal Characteristics**

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		2N5400	
P <sub>D</sub>	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

# PNP General Purpose Amplifier (continued)

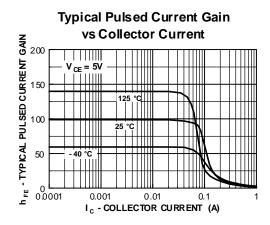
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 1.0 \text{ mA}, I_B = 0$	120		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 100  \mu A, I_E = 0$	130		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10  \mu A, I_C = 0$	5.0		V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 100 V, I <sub>E</sub> = 0		100	nA
		$V_{CB} = 100 \text{ V}, I_{E} = 0, T_{A} = 100 ^{\circ}\text{C}$		100	μΑ
I <sub>EBO</sub>	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$		50	nA
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$V_{CE} = 5.0 \text{ V}, I_{C} = 50 \text{ mA}$ $I_{C} = 10 \text{ mA}, I_{B} = 1.0 \text{ mA}$	40	0.2	V
\ /	Collector Froitter Catringtion Voltage		40	0.0	\/
OL(OCK)		$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		0.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$		1.0	V
		$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		1.0	V
SMALL S	IGNAL CHARACTERISTICS				
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, f = 1.0 MHz		6.0	pF
f⊤	Current Gain - Bandwidth Product	$I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V},$ f = 100  MHz	100	400	
h <sub>fe</sub>	Small-Signal Current Gain  Noise Figure	$I_C = 1.0 \text{ mA}, V_{CE} = 10 \text{ V},$ f = 1.0  kHz	30	200	
NF		$V_{CE} = 5.0 \text{ V}, I_{C} = 250 \mu\text{A},$	·	8.0	V

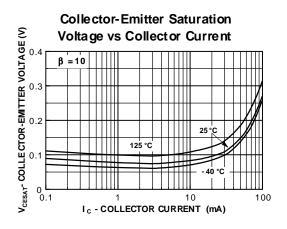
<sup>\*</sup>Pulse Test: Pulse Width £ 300 ms, Duty Cycle £ 2.0%

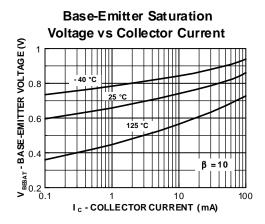
# **PNP General Purpose Amplifier**

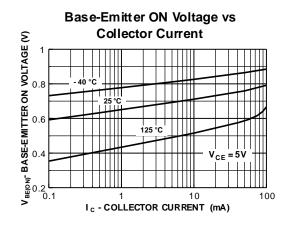
(continued)

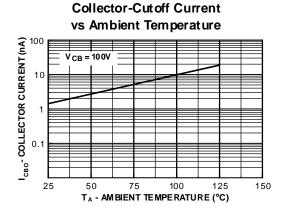
# **Typical Characteristics**

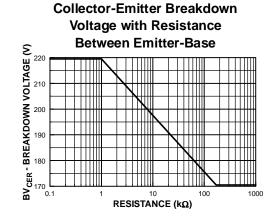








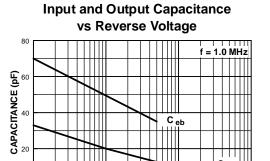




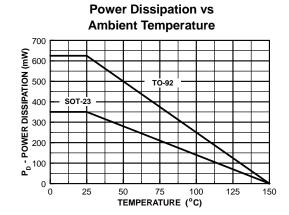
# **PNP General Purpose Amplifier**

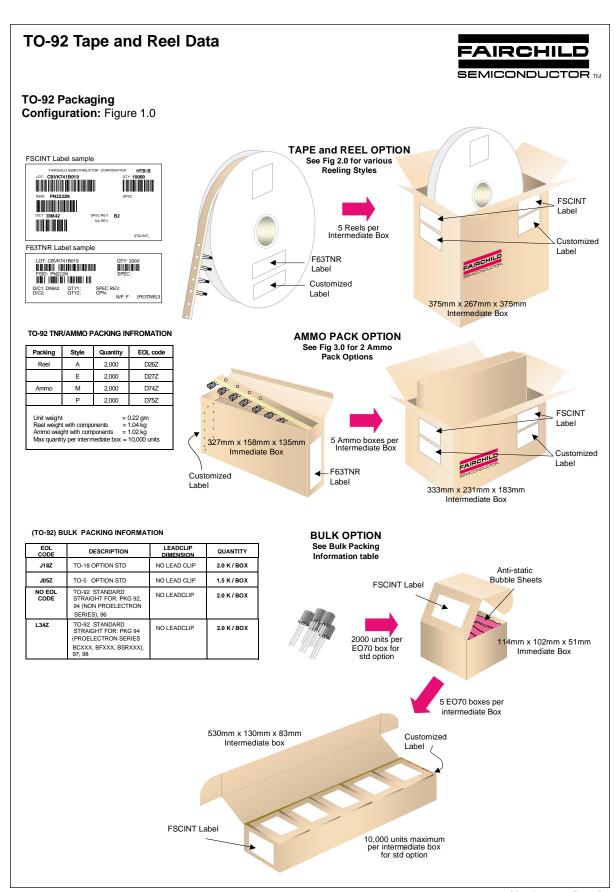
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# Typical Characteristics (continued)



V<sub>R</sub> - REVERSE BIAS VOLTAGE(V)



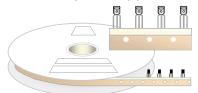


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# TO-92 Tape and Reel Data, continued

# **TO-92 Reeling Style Configuration:** Figure 2.0

# Machine Option "A" (H)

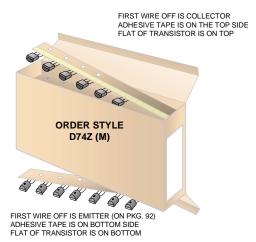


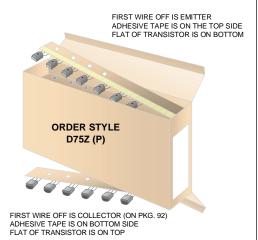
Style "A", D26Z, D70Z (s/h)

# Machine Option "E" (J)

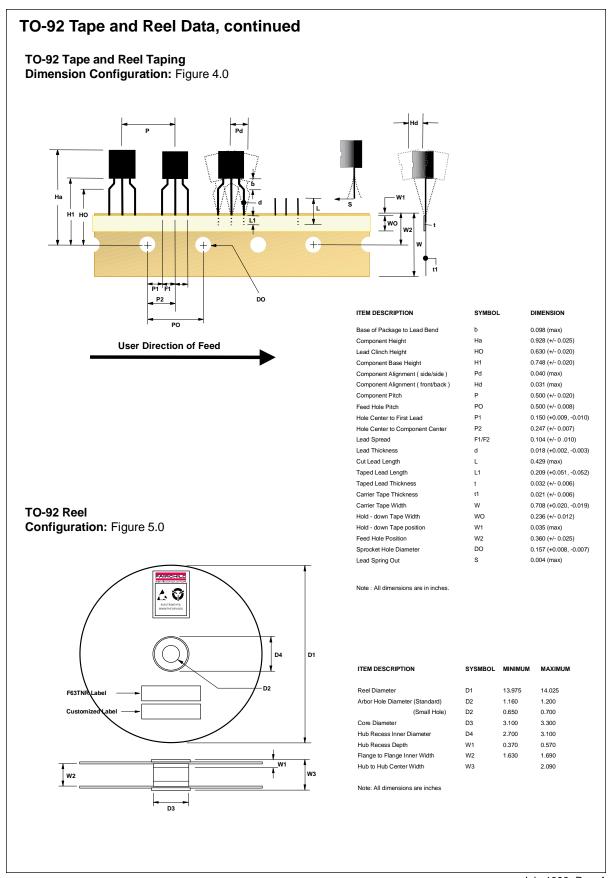
Style "E", D27Z, D71Z (s/h)

# **TO-92 Radial Ammo Packaging Configuration:** Figure 3.0





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# **TO-92 Package Dimensions** FAIRCHILD SEMICONDUCTOR TM TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 0.185 4.70 0.170 4.32 TO-92 (92,94,96) 94 96 B F В В В D D 2 В S С G Ε Ø0.060 [Ø1.52] G В S С G 0.010 [0.254] DEEP 5.0°TYP.

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0.095 0.084 2.13

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